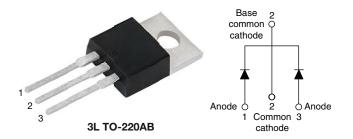


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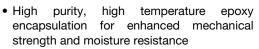
# High Performance Schottky Rectifier, 2 x 10 A



PRIMARY CHARACTERISTICS								
I <sub>F(AV)</sub>	2 x 10 A							
$V_{R}$	80 V, 90 V, 100 V							
V <sub>F</sub> at I <sub>F</sub>	0.70 V							
I <sub>RM</sub> max.	6 mA at 125 °C							
T <sub>J</sub> max.	150 °C							
E <sub>AS</sub>	24 mJ							
Package	3L TO-220AB							
Circuit configuration	Common cathode							

### **FEATURES**

- 150 °C T<sub>J</sub> operation
- Low forward voltage drop
- · High frequency operation





- Guard ring for enhanced ruggedness and long term reliability
- Designed and qualified according to JEDEC®-JESD 47
- Material categorization: for definitions of compliance please see <a href="https://www.vishay.com/doc?99912"><u>www.vishay.com/doc?99912</u></a>

#### **DESCRIPTION**

This center tap Schottky rectifier has been optimized for low reverse leakage at high temperature. The proprietary barrier technology allows for reliable operation up to 150 °C junction temperature. Typical applications are in switching power supplies, converters, freewheeling diodes, and reverse battery protection.

MAJOR RATINGS AND CHARACTERISTICS								
SYMBOL	CHARACTERISTICS	VALUES	UNITS					
I <sub>F(AV)</sub>	Rectangular waveform (per device)	20	А					
I <sub>FRM</sub>	T <sub>C</sub> = 133 °C per leg	20	А					
V <sub>RRM</sub>		80/100	V					
I <sub>FSM</sub>	t <sub>p</sub> = 5 μs sine	850	А					
V <sub>F</sub>	10 A <sub>pk</sub> , T <sub>J</sub> = 125 °C	0.70	V					
T <sub>J</sub>	Range	-65 to +150	°C					

VOLTAGE RATINGS									
PARAMETER SYMBOL MBR2080CT-M3 MBR2090CT-M3 MBR20100CT-M3 UNIT									
Maximum DC reverse voltage	$V_R$	80	90	100	V				
Maximum working peak reverse voltage	$V_{RWM}$	00	90	100	\ \ \				

ABSOLUTE MAXIMUM RATINGS								
PARAMETER		SYMBOL	TEST CONDITIONS		VALUES	UNITS		
Maximum average	Maximum average per leg		T 100.00 mindly		10			
forward current	per device	$T_{C} = 133 ^{\circ}\text{C}, \text{ rated } V_{R}$		20				
Peak repetitive forward current per leg		I <sub>FRM</sub>	Rated V <sub>R</sub> , square wave, 20 kHz, T <sub>C</sub> = 133 °C		20			
Non-repetitive peak surge current		I <sub>FSM</sub>	5 μs sine or 3 μs rect. pulse	Following any rated load condition and with rated V <sub>RRM</sub> applied	850	Α		
			Surge applied at rated load conditions halfwave, single phase, 60 Hz		150			
Peak repetitive reverse surge current		I <sub>RRM</sub>	2.0 μs, 1.0 kHz		0.5			
Non-repetitive avalanche energy per leg		E <sub>AS</sub>	T <sub>J</sub> = 25 °C, I <sub>AS</sub> = 2 A, L = 12 mH		24	mJ		

Revision: 18-Aug-17 1 Document Number: 96282



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ELECTRICAL SPECIFICATIONS								
PARAMETER	SYMBOL	TEST CON	VALUES	UNITS				
		10 A	T <sub>.1</sub> = 25 °C	0.80				
Maximum forward voltage drap	V <sub>FM</sub> <sup>(1)</sup>	20 A	1j=25 C	0.95	V			
Maximum forward voltage drop	V <sub>FM</sub> (··)	10 A	T 105 °C	0.70	V			
		20 A	T <sub>J</sub> = 125 °C	0.85				
Maximum instantaneous reverse current	I <sub>RM</sub> <sup>(1)</sup>	T <sub>J</sub> = 25 °C	Rated DC voltage	0.10	mΛ			
Maximum instantaneous reverse current		T <sub>J</sub> = 125 °C	Rated DC voltage	6	mA			
Threshold voltage	V <sub>F(TO)</sub>	$T_J = T_J$ maximum		0.433	V			
Forward slope resistance	r <sub>t</sub>			15.8	mΩ			
Maximum junction capacitance	C <sub>T</sub>	V <sub>R</sub> = 5 V <sub>DC</sub> (test signal rang	400	pF				
Typical series inductance	L <sub>S</sub>	Measured from top of termi	8.0	nH				
Maximum voltage rate of change	dV/dt	Rated V <sub>R</sub>	10 000	V/µs				

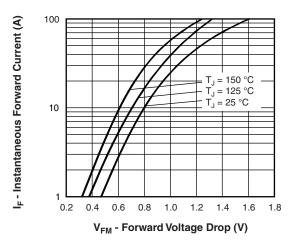
#### Note

 $^{(1)}\,$  Pulse width < 300 µs, duty cycle < 2 %

THERMAL - MECHANICAL SPECIFICATIONS								
PARAMETER		SYMBOL	TEST CONDITIONS	VALUES	UNITS			
Maximum junction temper	erature range	T <sub>J</sub>		-65 to +150	°C			
Maximum storage tempe	rature range	T <sub>Stg</sub>		-65 to +175				
Maximum thermal resista junction to case per leg	ance,	R <sub>thJC</sub>	DC operation	2.0				
Typical thermal resistance, case to heatsink		R <sub>thCS</sub>	Mounting surface, smooth and greased (Only for TO-220)	smooth and greased 0.50				
Maximum thermal resistance, junction to ambient		R <sub>thJA</sub>	DC operation (For D <sup>2</sup> PAK and TO-262)	50				
Approximate weight				2	g			
Approximate weight				0.07	OZ.			
Mounting torque	ing torque minimum maximum			6 (5)	kg∙ cm			
woulding torque				12 (10)	(lbf·in)			
Marking device			Case style 3L TO-220AB	MBR2 MBR2 MBR20	090CT			

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100 I<sub>R</sub> - Reverse Current (mA) 10 T<sub>1</sub> = 125 °C 0.1 0.01 0.001  $T_1 = 25 \, ^{\circ}C$ 0.0001 0 20 40 60 80 100 V<sub>R</sub> - Reverse Voltage (V)

Fig. 1 - Maximum Forward Voltage Drop Characteristics (Per Leg)

Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage (Per Leg)

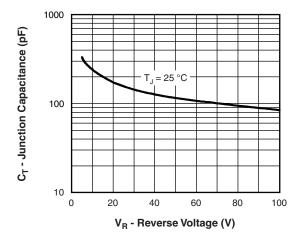


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage (Per Leg)

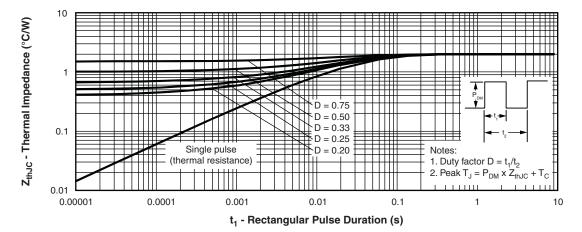


Fig. 4 - Maximum Thermal Impedance Z<sub>thJC</sub> Characteristics (Per Leg)

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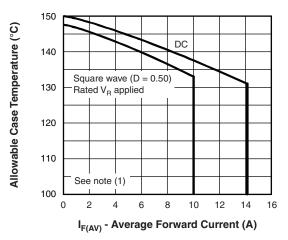


Fig. 5 - Maximum Allowable Case Temperature vs. Average Forward Current (Per Leg)

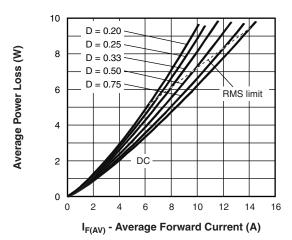


Fig. 6 - Forward Power Loss Characteristics (Per Leg)

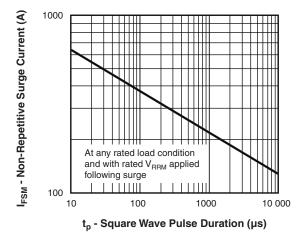


Fig. 7 - Maximum Non-Repetitive Surge Current (Per Leg)

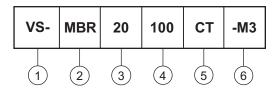
#### Note

 $^{(1)}$  Formula used: T<sub>C</sub> = T<sub>J</sub> - (Pd + Pd<sub>REV</sub>) x R<sub>thJC</sub>; Pd = forward power loss = I<sub>F(AV)</sub> x V<sub>FM</sub> at (I<sub>F(AV)</sub>/D) (see fig. 6); Pd<sub>REV</sub> = inverse power loss = V<sub>R1</sub> x I<sub>R</sub> (1 - D); I<sub>R</sub> at V<sub>R1</sub> = rated V<sub>R</sub>

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### **ORDERING INFORMATION TABLE**

Device code



Vishay Semiconductors product

- Schottky MBR series

- Current rating (20 = 20 A)

080 = 80 V

4

Voltage ratings

090 = 90 V

듬

- CT = essential part number

100 = 100 V

믬

- Environmental digit

-M3 = halogen-free, RoHS-compliant, and termination lead (Pb)-free

ORDERING INFORMATION (Example)										
PREFERRED P/N	QUANTITY PER T/R	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION							
VS-MBR2080CT-M3	50	1000	Antistatic plastic tube							
VS-MBR2090CT-M3	50	1000	Antistatic plastic tube							
VS-MBR20100CT-M3	50	1000	Antistatic plastic tube							

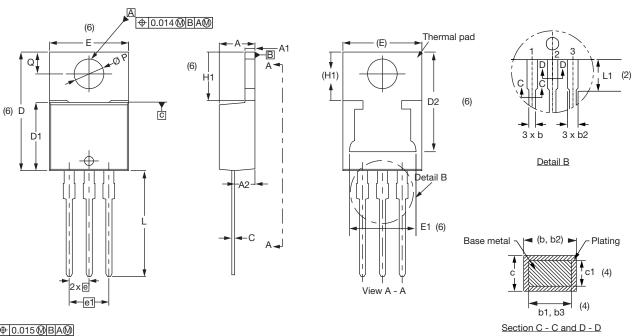
LINKS TO RELATED DOCUMENTS							
Dimensions <u>www.vishay.com/doc?96154</u>							
Part marking information	www.vishay.com/doc?95028						



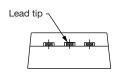
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## **3L TO-220AB**

### **DIMENSIONS** in millimeters and inches



### **⊕** 0.015 **M** B A **M**



Conforms to JEDEC® outline TO-220AB

SYMBOL	MILLIM	IETERS	INC	HES	NOTES	NOTES	SYMBOL	MILLIMETERS		INCHES		NOTES
STWIBOL	MIN.	MAX.	MIN.	MAX.	NOTES		STIMBOL	MIN.	MAX.	MIN.	MAX.	NOTES
Α	4.25	4.65	0.167	0.183			D2	11.68	13.30	0.460	0.524	6, 7
A1	1.14	1.40	0.045	0.055			E	10.11	10.51	0.398	0.414	3, 6
A2	2.50	2.92	0.098	0.115			E1	6.86	8.89	0.270	0.350	6
b	0.69	1.01	0.027	0.040			е	2.41	2.67	0.095	0.105	
b1	0.38	0.97	0.015	0.038	4		e1	4.88	5.28	0.192	0.208	
b2	1.20	1.73	0.047	0.068			H1	6.09	6.48	0.240	0.255	6
b3	1.14	1.73	0.045	0.068	4		L	13.52	14.02	0.532	0.552	
С	0.36	0.61	0.014	0.024			L1	3.32	3.82	0.131	0.150	2
c1	0.36	0.56	0.014	0.022	4		ØΡ	3.54	3.91	0.139	0.154	
D	14.85	15.35	0.585	0.604	3		Q	2.60	3.00	0.102	0.118	
D1	8.38	9.02	0.330	0.355		1		•			•	

### **Notes**

- <sup>(1)</sup> Dimensioning and tolerancing as per ASME Y14.5M-1994
- (2) Lead dimension and finish uncontrolled in L1
- (3) Dimension D, D1, and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outermost extremes of the plastic body
- (4) Dimension b1, b3, and c1 apply to base metal only
- Controlling dimensions: inches
- (6) Thermal pad contour optional within dimensions E, H1, D2, and E1
- (7) Outline conforms to JEDEC® TO-220, except D2



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SK33B-TP SK35A-TP SK38B-TP NRVBM120LT1G NTE505 NTSB30U100CT-1G SS15E-TP VS-6CWQ10FNHM3 ACDBA1100LR-HF
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